## NSN 5962-01-130-8657



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-130-8657 **Body Length:** Between 0.955 inches and 1.010 inches **Body Width:** Between 0.265 inches and 0.300 inches **Body Height:** Between 0.130 inches and 0.175 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Data link 76301 **Features Provided:** Hermetically sealed and programmed and w/enable and w/open collector **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 80.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Prom **Test Data Document:** 13499-351-1933 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a **Unit Of Measure:** 

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**Demilitarization:** Yes - demil/mli